

LC75281E

Parametric Equalizer System



Overview

The LC75281E is a <u>four-band stereo</u> parametric equalizer. A parametric equalizer is a fully general equalizer that allows all three parameters that define an equalizer's characteristics, i.e., the center frequency, gain, and Q, to be set independently.

Functions

- Four-band (low, low mid, high mid, and high) left and right channels parametric equalizer
- For each band:

Center frequency: 11 positions

Gain: 13 positions in ±2dB steps Q: Variable over 8 positions

• The center frequency, gain, and Q control settings are set using serial data input in the CCB format.

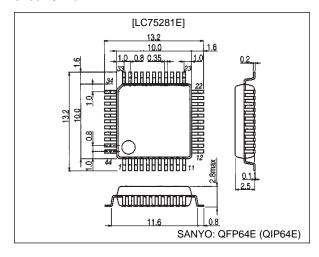
Features

- A parametric equalizer with the following features can be implemented with just two ICs: this IC and a microcontroller.
- The center frequency, gain, and Q can be controlled by a single operation.
- Memory recall by a single operation can be implemented using preset values.
- Either shelving or peaking characteristics can be selected for the low band.

Package Dimensions

unit: mm

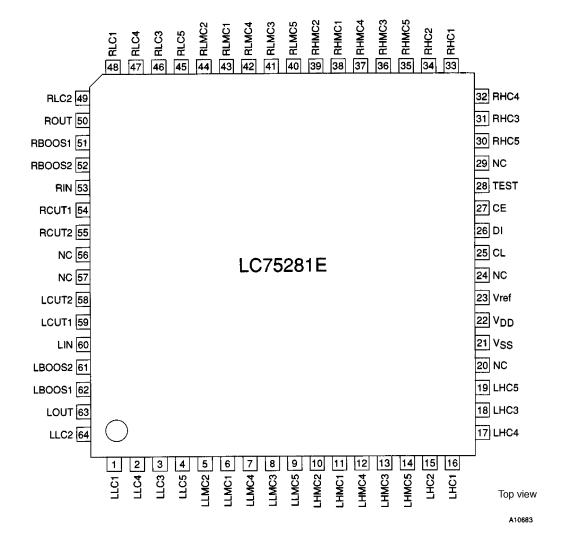
3159-QFP64E



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Pin Assignment



Specifications Absolute Maximum Ratings at $Ta=25^{\circ}C,\,V_{SS}=0~V$

Parameter	Symbol	Conditions	Ratings	Unit
Maximum supply voltage	V _{DD} max		10.5	V
Marrianna in most valta an	V _{IN} 1 max	LIN, RIN	0 to V _{DD}	V
Maximum input voltage	V _{IN} 2 max	CL, CE, DI	0 to V _{DD}	V
Allowable power dissipation	Pd max	Ta ≤ 85°C	300	mW
Operating temperature	Topr		-40 to +85	°C
Storage temperature	Tstg		-50 to +125	°C

Allowable Operating Ranges at $Ta = -40 \ to \ +85^{\circ}C, \ V_{SS} = 0 \ V$

Parameter	Symbol	Conditions		Unit		
Parameter	Symbol	Conditions	min	typ	max	Oill
Supply voltage	V_{DD}		6.0		9.0	V
High-level input voltage	V _{IH}	CL, CE, DI	4.0		V_{DD}	V
Low-level input voltage	V _{IL}	CL, CE, DI	V _{SS}		1.0	V
Input voltage range	V _{IN}	LIN, RIN	0		V _{DD}	V
Load resistance	R _L	LOUT, ROUT, MIXOUT	1			kΩ
Input pulse width	tøw	CL	1			μs
Setup time	tsetup	CL, CE, DI	1			μs
Hold time	thold	CL, CE, DI	1			μs
Operating frequency	fopg	CL			500	kHz

Electrical Characteristics at $Ta=25^{\circ}C,\,f=1~kHz,\,V_{DD}=8~V,\,V_{SS}=0~V$

Parameter	Cumbal	Conditions		Unit		
Parameter	Symbol	Conditions	min	typ	max	Offic
Current drain	I _{DD}	V _{DD}		36	50	mA
Output voltage	Vo	LOUT, ROUT: THD = 1%		2.2		Vrms
	THD1	LOUT, ROUT: Vo = Flat, V _{IN} = 0 dBV		0.005	0.01	%
Total harmonic distortion	THD2	LOUT, ROUT: Vo = Boost,		0.1	1	0/
	IHDZ	All bands +2 dB, $V_{IN} = -15 \text{ dBV}$		0.1		%
	V 4	LOUT, ROUT: Vo = Flat,		7	15	
	V _N 1	Rg = 1 k Ω , IHF-A filters		/		μs
	1/ 0	LOUT, ROUT: Vo = Flat,		40		
Output noise voltage	V _N 2	Rg = 1 k Ω , DIN filters		13		μs
	V _N 3	LOUT, ROUT, Rg = 1 k Ω , f0 = f1, Q = Q1 IHF-A filter, all bands at full boost, with the external constants the same as those for the center frequency (example 1)		58		μs
	V _N 4	LOUT, ROUT, Rg = 1 k Ω , f0 = f1, Q = Q1 IHF-A filters, all bands at full cut, with the external constants the same as those for the center frequency (example 1)		23		μs
Crosstalk between inputs	CT	V _{IN} = 1 Vrms, f = 1 kHz	60	80		dB
DC variation V _{DC} With the external consta		CL, DI, CE, V _{IN} = 9 V			1	μA
		CL, DI, CE, V _{IN} = 0 V	-1			μΑ
		All bands G = +12 dB, Q: Setting switched from Q1 to Q2 With the external constants the same as those for the center frequency (example 1) shown on page 7.	-10		+10	mV

Pin Functions

Pin No.	Pin	Function
64	LLC2	
1	LLC1	Left channel low band control block.
2	LLC4	
3	LLC3	External capacitor connections.
4	LLC5	
5	LLMC2	
6	LLMC1	Left channel low mid band control block.
7	LLMC4	External capacitor connections.
8	LLMC3	External capacitor connections.

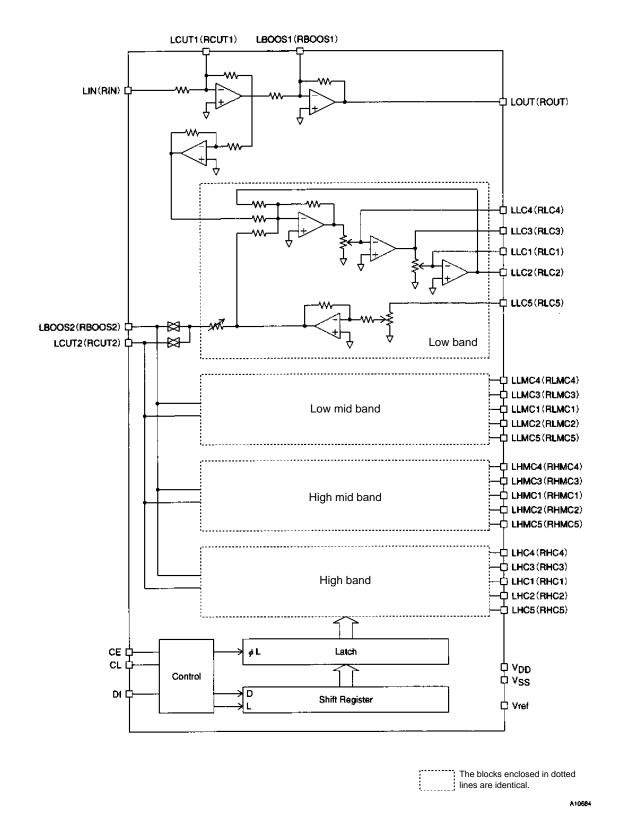
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Pin No.	Pin	Function
10	LHMC2	
11	LHMC1	
12	LHMC4	Left channel high mid band control block.
13	LHMC3	External capacitor connections.
14	LHMC5	
15	LHC2	
16	LHC1	
17	LHC4	Left channel high band control block.
18	LHC3	External capacitor connections.
19	LHC5	
20, 24, 29	LHCS	
56, 57	NC	Unused pins. These pins must be either left open or connected to V _{SS} .
55,51		Internal operational amplifier reference voltage generator outputs.
23	Vref	Several capacitors with values of about 10 µF must be connected with this pin to reduce ripple.
21	V _{SS}	Power supply.
22	V _{DD}	These pins must be connected to the stipulated power supply.
		Chip enable input. Data is written to the internal latch and the analog switches operate when this pin
27	CE	changes from high to low. Data transfer is enabled when this pin is high.
26	DI	Serial data and clock inputs for IC control
25	CL	· ·
49	RLC2	
48	RLC1	Right channel low band control block.
47	RLC4	External capacitor connections.
46	RLC3	· ·
45	RLC5	
44	RLMC2	
43	RLMC1	Right channel low mid band control block.
42	RLMC4	External capacitor connections.
41	RLMC3	
40	RLMC5	
39	RHMC2	
38	RHMC1	Right channel high mid band control block.
37	RHMC4	External capacitor connections.
36	RHMC3	
35	RHMC5	
34	RHC2	
33	RHC1	Right channel high band control block.
32	RHC4	External capacitor connections.
31	RHC3	External capacitor confidencies.
30	RHC5	
58	LCUT2	Internal filter DC offset voltage exclusion canacitor connections
59	LCUT1	Internal filter DC offset voltage exclusion capacitor connections.
61	LBOOS2	Capacitors of about 10 µF must be connected between pins 61 and 62, and between pins 63 and 64.
62	LBOOS1	(These are for the left channel block.)
55	RCUT2	Internal filter DC offeet voltage evaluation connections
54	RCUT1	Internal filter DC offset voltage exclusion capacitor connections.
52	RBOOS2	Capacitors of about 10 μF must be connected between pins 51 and 52, and between pins 49 and 50.
51	RBOOS1	(These are for the right channel block.)
60	LIN	Left channel audio signal input (Must be driven with a low load capacitance.)
53	RIN	Right channel audio signal input (Must be driven with a low load capacitance.)
63	LOUT	Left channel audio signal output (Must be received with a low load capacitance.)
50	ROUT	Right channel audio signal output (Must be received with a low load capacitance.)
28	TEST	IC test pin.
		This pin must be left open when not used for IC test.

Block Diagram



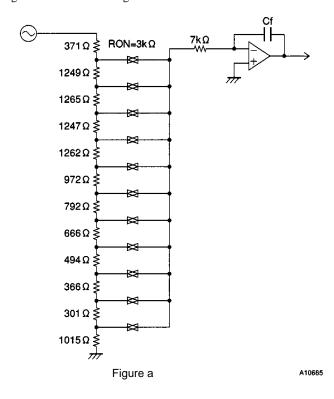
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• Center frequency (fo)

Band	f1	f2	f3	f4	f5	f6	f7	f8	f9	f10	f11	External capacitor (µF)
Low	31.5	40	50	63	80	100	125	160	200	250	315	0.047
Low mid	160	200	250	315	400	500	630	800	1 k	1.25 k	1.6 k	0.0094
High mid	630	800	1 k	1.25 k	1.6 k	2 k	2.5 k	3.15 k	4 k	5 k	6.3 k	0.00235
High	1.6 k	2 k	2.5 k	3.15 k	4 k	5 k	6.3 k	8 k	10 k	12.5 k	16 k	0.0094

External capacitor calculations

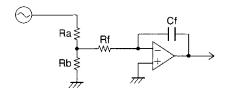
Figure a shows the LC75281E internal f0 control circuit. The center frequency f0 can be set to one of 11 frequencies in 1/3 octave steps by switching the resistors in the figure.



The value of the external capacitor C is determined by substituting the desired center frequency in the following formula.

$$Cf = \frac{1}{2\pi Rf \text{ fo max}} \bullet \frac{Rb//Rf}{Ra + (Rb//Rf)}$$

fo max: Corresponds to 315 Hz in the low band row in the preceding table.



Equivalent Circuit for Cf calculation

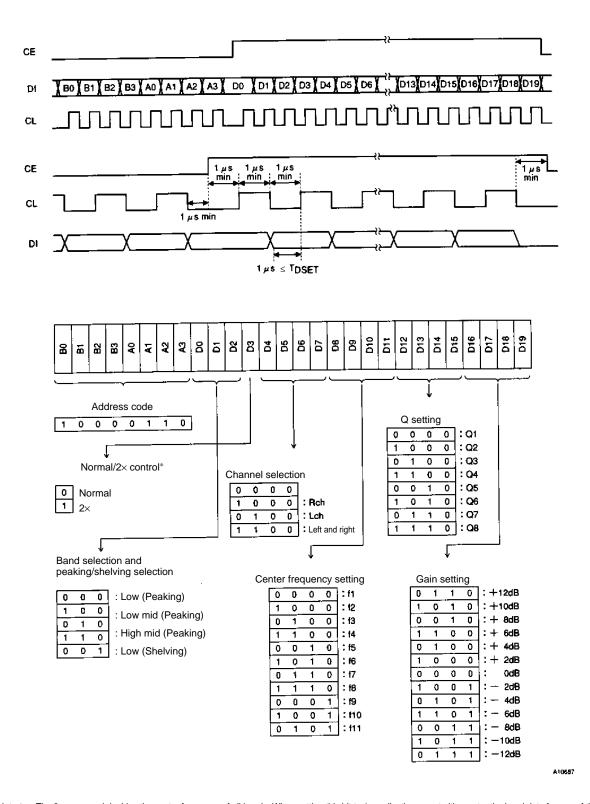
• Gain: 13 positions in 2-dB steps

• Q

	Q1	Q2	Q3	Q4	Q5	Q6	Q7	Q8
Q	0.404	0.667	1.41	2.15	2.87	4.32	5.76	8.65
OCT	3	2	1	2/3	1/2	1/3	1/4	1/6

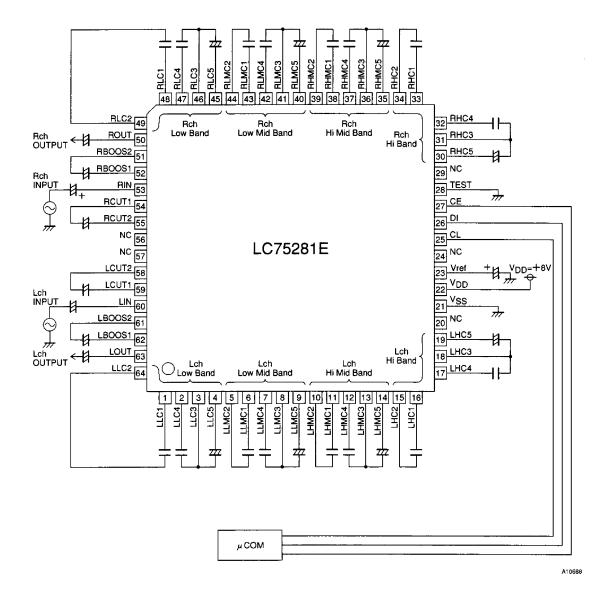
Data Input Procedure

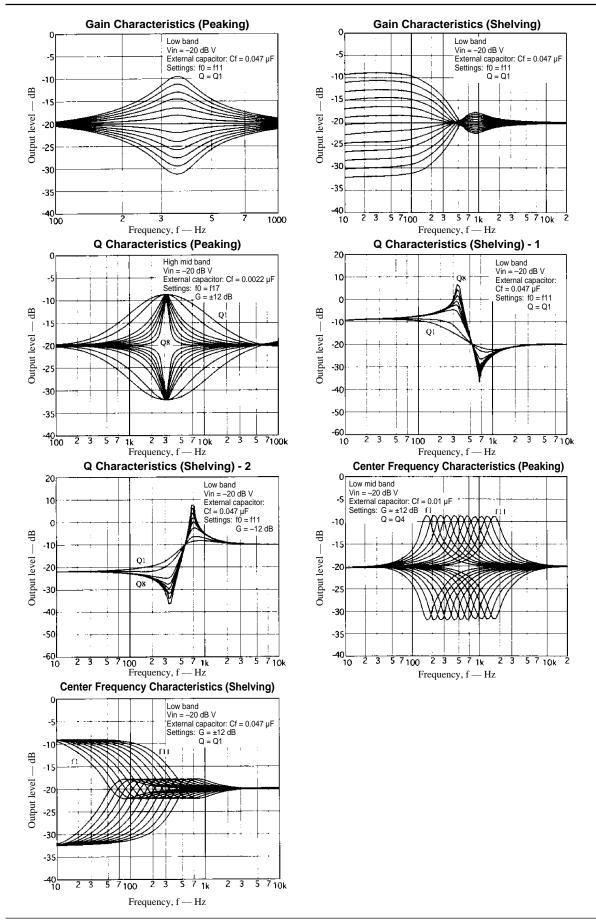
The LC75281E is controlled by inputting the stipulated serial data to the CE, CL, and DI pins. The data consists of 28 bits, of which 8 bits are the address and 20 bits are the data.



Note *: The 2× command doubles the center frequency of all bands. When setting this bit to 1, applications must either enter the band data for one of the bands in bits D1 to D19, or must set both bits D4 and D5 to 0, in which case all other bits are ignored.

Sample Application Circuit





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